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Silicon NPN Epitaxial

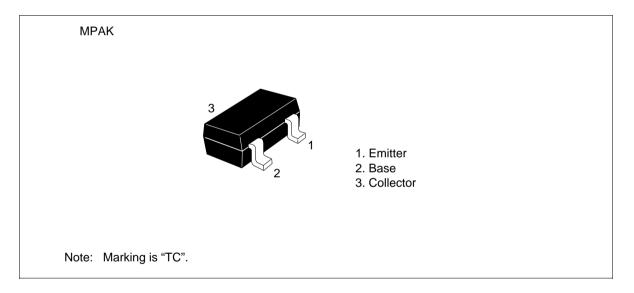


ADE-208-1076 (Z) 1st. Edition Mar. 2001

#### Application

- UHF/VHF frequency converter
- Local oscillator

#### Outline



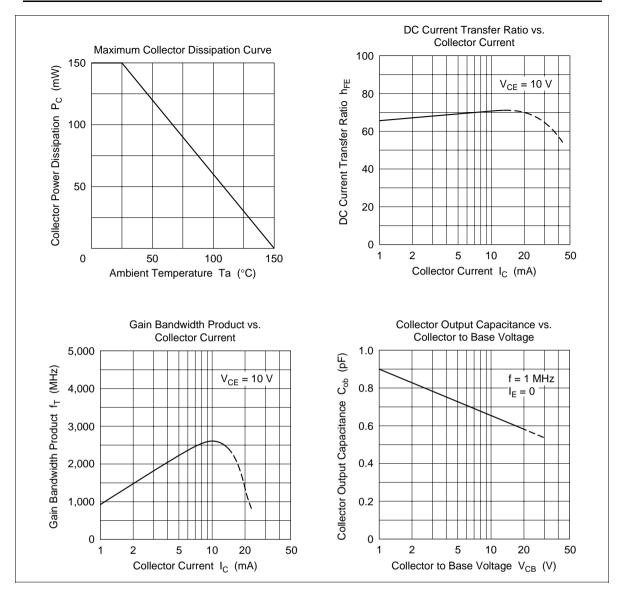
## **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

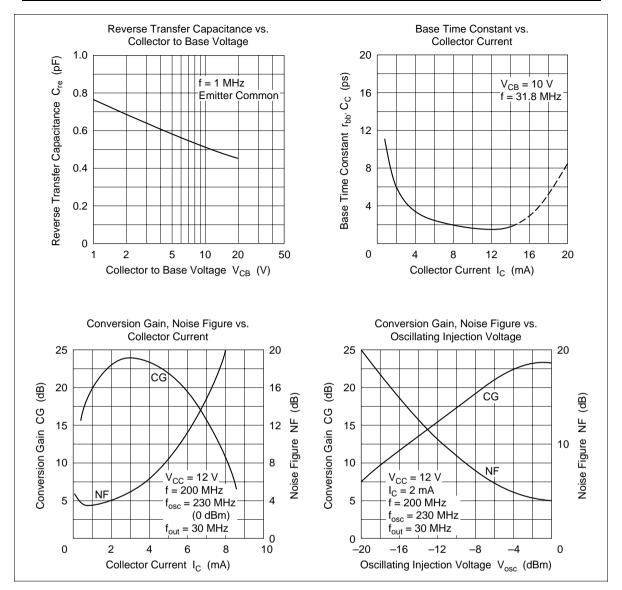
Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	30	V
Collector to emitter voltage	V <sub>CEO</sub>	20	V
Emitter to base voltage	V <sub>EBO</sub>	3	V
Collector current	Ι <sub>c</sub>	50	mA
Collector power dissipation	Pc	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

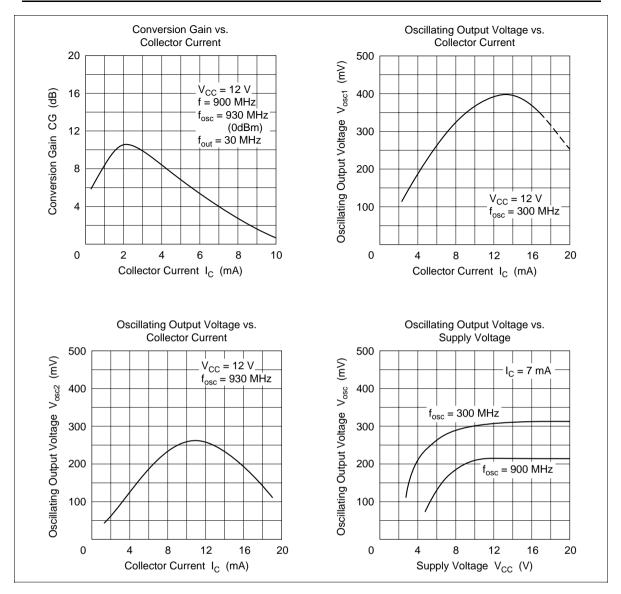
#### **Electrical Characteristics** (Ta = 25°C)

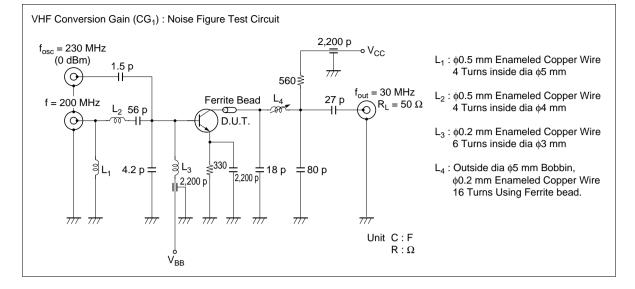
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{\rm (BR)CBO}$	30	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{\rm (BR)CEO}$	20	_	_	V	$I_c = 1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	3	_	_	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I <sub>CBO</sub>		_	500	nA	$V_{\rm CB} = 15 \text{ V}, I_{\rm C} = 0$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	0.7	V	$I_{c} = 10 \text{ mA}, I_{B} = 5 \text{ mA}$
DC current transfer ratio	h <sub>FE</sub>	30	_	200		$V_{ce} = 10 \text{ V}, \text{ I}_{c} = 5 \text{ mA}$
Collector output capacitance	Cob	_	_	1.0	pF	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz
Gain bandwidth product	f <sub>⊤</sub>	1400	2200	_	MHz	$V_{ce} = 10 \text{ V}, \text{ I}_{c} = 5 \text{ mA}$
Conversion gain	CG1	_	22.5	_	dB	$V_{cc} = 12 \text{ V}, I_c = 2 \text{ mA},$ f = 200 MHz, f <sub>osc</sub> = 230 MHz (0dBm)
	CG <sub>2</sub>	_	10	_	dB	$V_{cc} = 12 \text{ V}, I_c = 2 \text{ mA},$ f = 900 MHz, f <sub>osc</sub> = 930 MHz (0dBm), f <sub>out</sub> = 30 MHz
Noise figure	NF	_	4.0	_	dB	$V_{cc} = 12 \text{ V}, I_c = 2 \text{ mA},$ f = 200 MHz, f <sub>osc</sub> = 230 MHz (0dBm)
Oscillating output voltage	V <sub>osc1</sub>	—	300	_	mV	$V_{cc}$ = 12 V, I <sub>c</sub> = 7 mA, f <sub>osc</sub> = 300 MHz
	V <sub>osc2</sub>		200		mV	$V_{cc}$ = 12 V, I <sub>c</sub> = 7 mA, f <sub>osc</sub> = 930 MHz

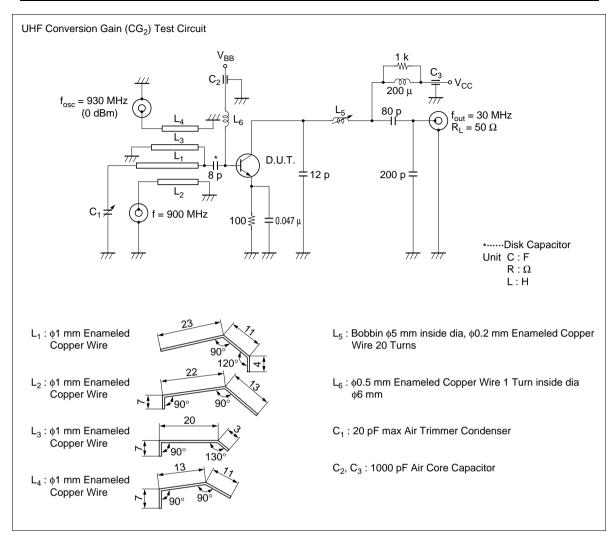




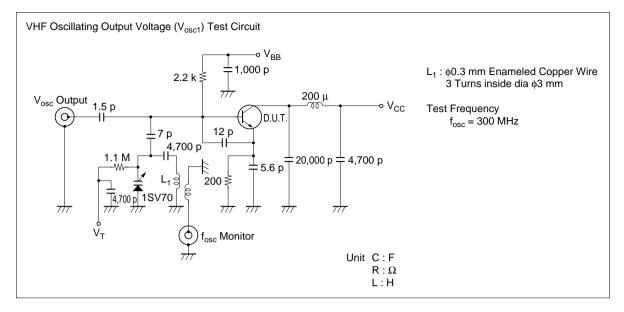


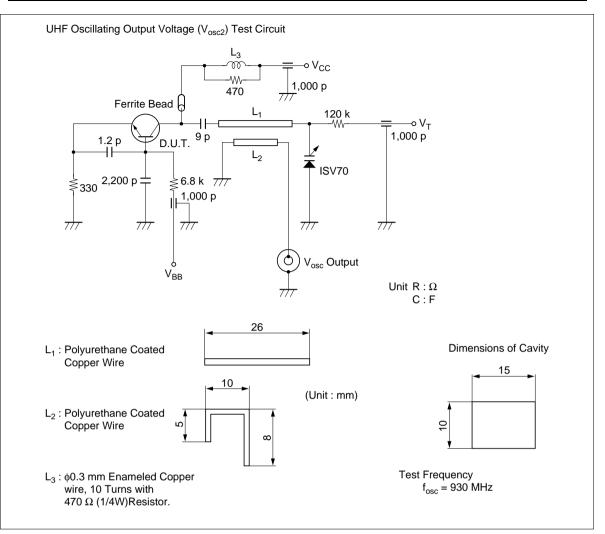






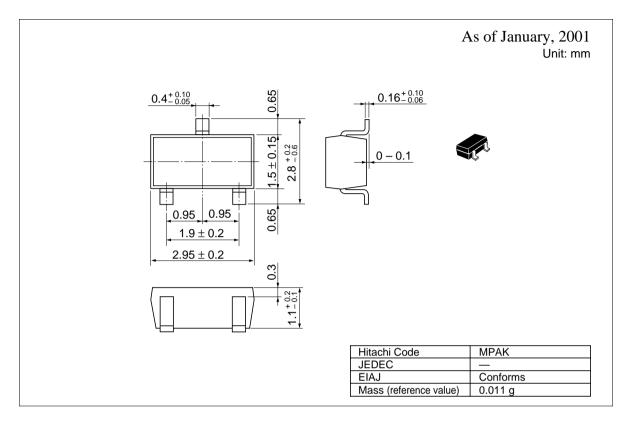








#### **Package Dimensions**



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